



| | |
|----------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|  | <h2 style="color: red;">DMT2004UFDF-13</h2> |
| | <p>Hersteller-Teilenummer: DMT2004UFDF-13</p> <p>Hersteller / Marke: Diodes Incorporated</p> <p>Teil der Beschreibung: MOSFET NCH 24V 14.1A UDFN2020</p> <p>Datenblätter:  DMT2004UFDF-13.pdf</p> <p>RoHS Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation. See specs for product details.</p> | |









Spezifikationen

| | |
|--------------------------------------------------|-----------------------------------------------------------------------------------|
| Teilenummer | DMT2004UFDF-13 |
| Hersteller | Diodes Incorporated |
| Beschreibung | MOSFET NCH 24V 14.1A UDFN2020 |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs , |
| Teilstatus | Require For Quote & Check Stock |
| VGS (th) (Max) @ Id | 1.45V @ 250µA |
| Technologie | MOSFET (Metal Oxide) |
| Supplier Device-Gehäuse | U-DFN2020-6 (Type B) |
| Serie | Automotive, AEC-Q101 |
| Rds On (Max) @ Id, Vgs | 6 mOhm @ 9A, 10V |
| Verlustleistung (max) | 800mW (Ta), 12.5W (Tc) |
| Verpackung | Tape & Reel (TR) |
| Verpackung / Gehäuse | 6-UDFN Exposed Pad |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Eingabekapazität (Ciss) (Max) @ Vds | 1683pF @ 15V |
| Gate Charge (Qg) (Max) @ Vgs | 53.7nC @ 10V |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 24V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 14.1A (Ta) |

DMT2004UFDF-13 Electronic Components ist ein 100% neues Original von YIC Distributor, DMT2004UFDF-13-Datenblätter durchsuchen, PDF, Inventar bei Y-IC.com Online, DMT2004UFDF-13 Diodes Incorporated mit Garantie und Vertrauen bestellen. Versand per DHL / FedEx / TNT / UPS Express. Unterstützung der Zahlung mit telegrafischer Überweisung (T / T) oder PayPal.

RFQ DMT2004UFDF-13 E-Mail: Info@Y-IC.com

Sie können auch interessiert

| | | | |
|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <p>sein:</p>  <p>DMT1W1K-F Cornell Dubilier Electronics (CDE) CAP FILM 1UF 10% 100VDC RADIAL</p> |  <p>DMT2004UFDF-7 Diodes Incorporated MOSFET NCH 24V 14.1A UDFN2020</p> |  <p>DMT2D22K-F Cornell Dubilier Electronics (CDE) CAP FILM 2200PF 10% 250VDC RAD</p> |  <p>DMT1S68K-F Cornell Dubilier Electronics (CDE) CAP FILM 0.068UF 10% 100VDC RAD</p> |
|  <p>DMT2004UFG-7 Diodes Incorporated MOSFET N-CH 24V 70A POWERDI3333</p> |  <p>DMT2004UPS-13 Diodes Incorporated MOSFET N-CH 24V 80A POWERDI5060</p> |  <p>DMT1S33K-F Cornell Dubilier Electronics (CDE) CAP FILM 0.033UF 10% 100VDC RAD</p> |  <p>DMT1S33K Cornell Dubilier Electronics (CDE) CAP FILM 0.033UF 10% 100VDC RAD</p> |

Verwandtes Hot-Keyword

Mehr

| | | | | |
|----------------------------------------------------|--------------------------------------------|---------------------------------------------|--------------------------------------|----------------------------------------------------|
| DMT2004UFDF-13 Diodes Incorporated | DMT2004UFDF-13 Datenblatt | DMT2004UFDF-13-Datenblätter | DMT2004UFDF-13 PDF | Diodes Incorporated DMT2004UFDF-13 |
| DMT2004UFDF-13 Electronic | DMT2004UFDF-13-Komponenten | DMT2004UFDF-13-Verteiler | DMT2004UFDF-13-Bild | DMT2004UFDF-13-Teil |
| DMT2004UFDF-13 Preis | DMT2004UFDF-13 Hersteller | DMT2004UFDF-13 Bild | DMT2004UFDF-13 Aktie | DMT2004UFDF-13 Inventar |
| DMT2004UFDF-13 Neu | DMT2004UFDF-13 Original | DMT2004UFDF-13 garantiert | DMT2004UFDF-13 RFQ | DMT2004UFDF-13 Online bestellen |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited